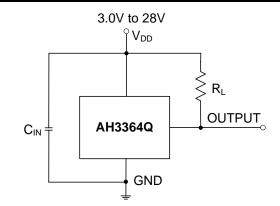


## **Typical Applications Circuit**



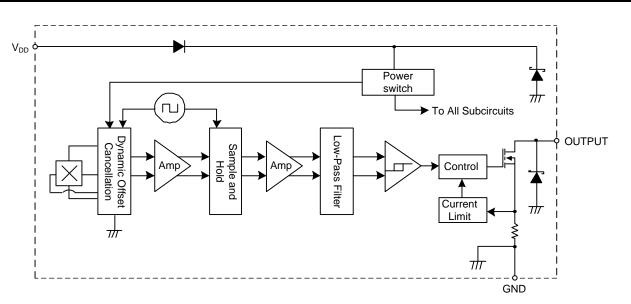
Note: 4.  $C_{IN}$  is for power stabilization and to strengthen the noise immunity, the recommended capacitance is 10nF ~ 100nF. R<sub>L</sub> is the pull-up resistor.

### **Pin Descriptions**

#### Package: SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

Pin Number	Pin Name	Function
1	V <sub>DD</sub>	Power Supply Input
2	GND	Ground
3	OUTPUT	Output Pin

# **Functional Block Diagram**





### Absolute Maximum Ratings (Note 5 & 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Characteristic		Value	Unit	
V <sub>DD</sub>	Supply Voltage (Note 6)		32	V	
V <sub>DDR</sub>	Reverse Supply Voltage (Note 6)		-32	V	
V <sub>OUT_MAX</sub>	Output Off Voltage (Note 6)		32	V	
I <sub>OUT</sub>	Continuous Output Current		60	mA	
I <sub>OUT_R</sub>	Reverse Output Current		-50	mA	
В	Magnetic Flux Density		Unlimited		
PD	Package Power Dissipation	SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)	550	mW	
		SOT23	230		
Ts	Storage Temperature Range		-65 to +165	°C	
TJ	Maximum Junction Temperature		+150	°C	
ESD HBM	Electros Static Discharge Withstand - Human Body Model (H	MB)	8	kV	
ESD MM	Electros Static Discharge Withstand - Machine Model (MM)		800	V	
ESD CDM	Electros Static Discharge Withstand - Charged Device Model	(CDM)	2	kV	

Notes: 5. Stresses greater than the 'Absolute Maximum Ratings' specified above may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be affected by exposure to absolute maximum rating conditions for extended periods of time.

6. The absolute maximum V<sub>DD</sub> of 32V is a transient stress rating and is not meant as a functional operating condition. It is not recommended to operate the device at the absolute maximum rated conditions for any period of time.

### Recommended Operating Conditions (@TA = -40°C to +150°C, unless otherwise specified.)

Symbol	Parameter	Condition	Rating	Unit
V <sub>DD</sub>	Supply Voltage	Operating	3.0 to 28	V
TA	Operating Temperature Range	Operating	-40 to +150	°C

## Electrical Characteristics (Note 7 & 8) (@T<sub>A</sub> = -40°C to +150°C, V<sub>DD</sub> = 3V to 28V, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
V <sub>OUT_ON</sub>	Output ON Voltage	I <sub>OUT</sub> = 20mA, B > Bop	-	0.2	0.4	V
I <sub>LKG</sub>	Output Leakage Current (When output is off)	V <sub>OUT</sub> = 28V, B < Brp, Output off	-	<0.1	10	μA
le e	Supply Current	Output open, $T_A = +25^{\circ}C$	-	3	3.5	mA
I <sub>DD</sub>	Supply Culterit	Output open, $T_A = -40^{\circ}C$ to $+150^{\circ}C$	-	-	4	mA
		$V_{DD} = -18V, T_A = +25^{\circ}C$	-	0.6	-	μA
	Reverse Supply Current	$V_{DD} = -18V$ , $T_A = -40^{\circ}C$ to $+150^{\circ}C$	-	0.6	1500	μA
I <sub>DD_R</sub>	Reverse Supply Current	$V_{DD} = -28V, T_A = +25^{\circ}C$	-	1.6	-	μA
		$V_{DD} = -28V$ , $T_A = -40^{\circ}C$ to $+150^{\circ}C$	-	1.6	2500	μA
t <sub>P_ON</sub>	Device Power-On Time (Start-up time)	$V_{DD} \ge 3V, B \ge Bop$ (Note 7)	-	10	-	μs
fc	Chopping Frequency	-	-	800	-	kHz
t <sub>D</sub>	Response Time Delay (Time from magnetic threshold reached to the start of the output rise or fall)	(Note 9)	-	3.75	-	μs
t <sub>R</sub>	Output Rising Time (External pull-up resistor R∟and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.2	1	μs
t <sub>F</sub>	Output Falling Time (Internal switch resistance and load capacitance dependent)	$R_L = 1k\Omega, C_L = 20pF$	-	0.1	1	μs
IOCL	Output Current Limit	B > Bop (Note 10)	30	-	55	mA
Vz	Zener Clamp Voltage	I <sub>DD</sub> = 5mA	28	-	-	V

Notes: 7. When power is initially turned on, Vbb must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

 Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

9. Guaranteed by design, process control and characterization. Not tested in production.

10. The device will limit the output current  $I_{OUT}$  to current limit of  $I_{OCL}$ .



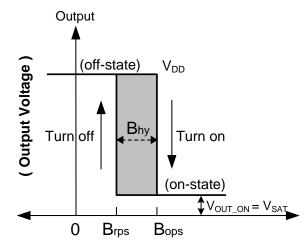
# **Magnetic Characteristics** (Note 11 &12) ( $T_A = -40^{\circ}C$ to $+150^{\circ}C$ , $V_{DD} = 3.0V$ to 28V, unless otherwise specified.)

				(	1mT=10 G	Gauss)
Symbol	Parameter	Condition	Min	Тур	Max	Unit
B <sub>OPS</sub> (South pole to the part marking		$V_{DD} = 12V, T_A = +25^{\circ}C$	-	80	-	
side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages)	Operation Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	60	80	100	
B <sub>RPS</sub> (South pole to the part marking		$V_{DD} = 12V, T_A = +25^{\circ}C$	-	60	-	Gauss
side of SOT23 and SIP-3 (Ammo Pack), SIP-3 (Bulk Pack) packages)	Release Point	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	40	60	80	Causs
Remark (IR)	Hysteresis (Note 13)	$V_{DD} = 12V, T_A = +25^{\circ}C$	-	20	-	
Bhy ( Bopx - Brpx )	Hysielesis (Note 13)	$T_{A} = -40^{\circ}C \text{ to } +150^{\circ}C$	14	20	29	

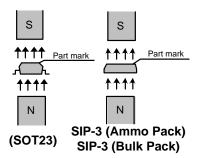
Notes: 11. When power is initially turned on, V<sub>DD</sub> must be within its correct operating range (3.0V to 28V) to guarantee the output sampling. The output state is valid after the start-up time of 10µs typical from the operating voltage reaching 3V.

12. Typical values are defined at T<sub>A</sub> = +25°C, V<sub>DD</sub> = 12V. Maximum and minimum values over the operating temperature range is not tested in production but guaranteed by design, process control and characterization.

13. Maximum and minimum hysteresis is guaranteed by design, process control and characterization.



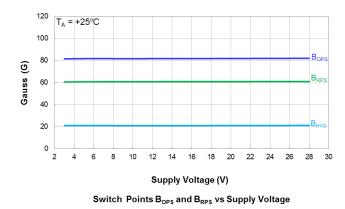
(Magnetic Flux Density B)

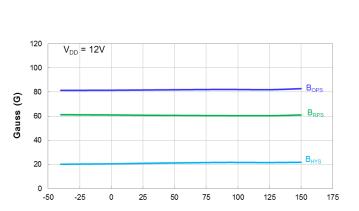




## **Typical Operating Characteristics**

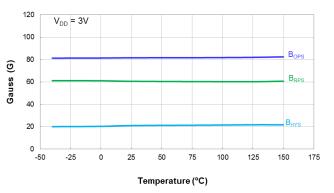
### Output Switch Operate and Release Points (Magnetic Thresholds) – $B_{OPS}$ and $B_{RPS}$



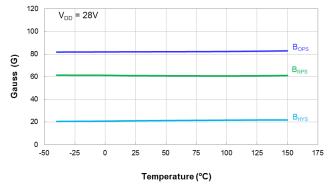


Temperature (°C)

Switch Points  $\mathbf{B}_{\text{OPS}}$  and  $\mathbf{B}_{\text{RPS}}$  vs Temperature

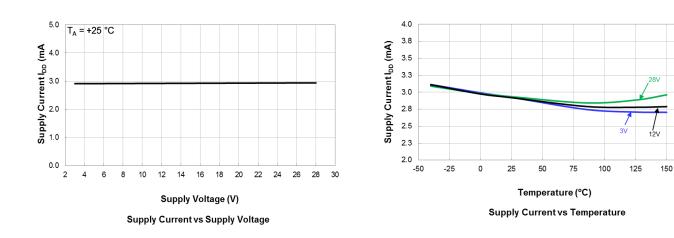


Switch Points  $B_{\text{OPS}}$  and  $B_{\text{RPS}}$  vs Temperature



Switch Points  $B_{\text{OPS}}$  and  $B_{\text{RPS}}$  vs Temperature

**Supply Current** 



175



28V

241

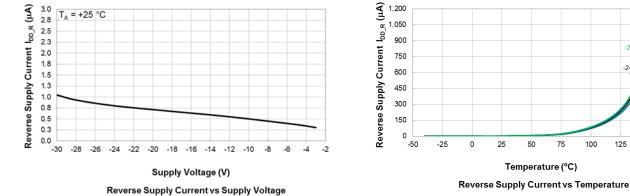
125

150

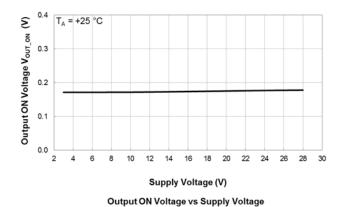
175

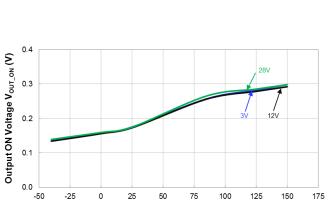
# Typical Operating Characteristics (Cont.)

### **Supply Reverse Current**



### **Output Switch On Voltage**



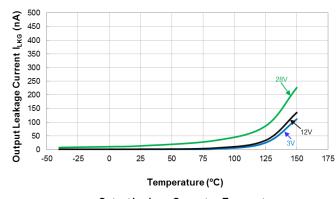


75

100

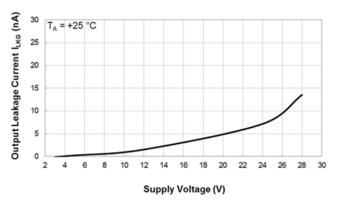
Temperature (°C)

Output ON Voltage vs Temperature



Output Leakage Current vs Temperature

### **Output Switch Leakage Current**

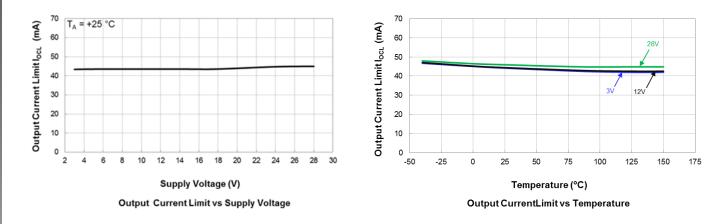


**Output Leakage Current vs Supply Voltage** 



# Typical Operating Characteristics (Cont.)

### Output Current Limit

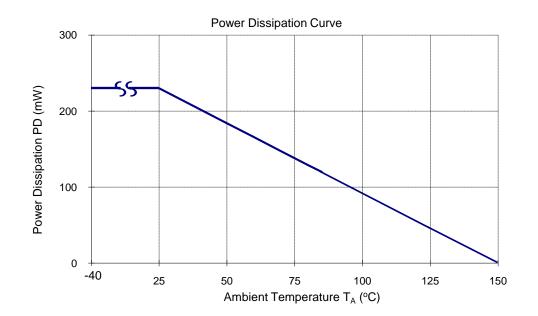




## **Thermal Performance Characteristics**

#### (1) Package type: SOT23

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	230	184	166	147	129	120	110	92	83	74	55	46	37	18	0



### (2) Package type: SIP-3

T <sub>A</sub> (°C)	25	50	60	70	80	85	90	100	105	110	120	125	130	140	150
P <sub>D</sub> (mW)	550	440	396	362	308	286	264	220	198	176	132	110	88	44	0

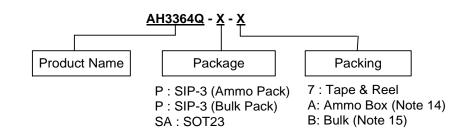
P<sub>D</sub> (mW)

Power Dissipation Curve





# **Ordering Information**

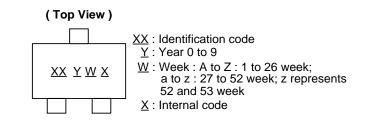


	Package		Bulk Box		7" Tape an	d Reel	Ammo Box		
Part Number	Code	Packaging	Quantity	Part Number Suffix	Quantity	Part Number Suffix	Quantity	Part Number Suffix	
AH3364Q-P-A	Р	SIP-3 (Ammo Pack)	NA	NA	NA	NA	4000/Box	-A	
AH3364Q-P-B	Р	SIP-3 (Bulk Pack)	1000	-B	NA	NA	NA	NA	
AH3364Q-SA-7	SA	SOT23	NA	NA	3000/Tape & Reel	-7	NA	NA	

Notes: 14. Ammo Box is for SIP-3 (Ammo Pack) Spread Lead. 15. Bulk is for SIP-3 (Bulk Pack) Straight Lead.

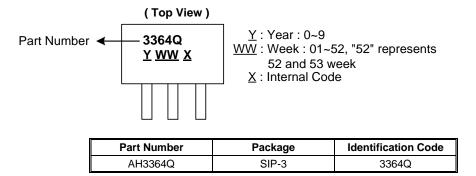
# **Marking Information**

### (1) Package Type: SOT23



ſ	Part Number	Package	Identification Code		
I	AH3364Q	SOT23	MG		

### (2) Package Type: SIP-3 (Ammo Pack), SIP-3 (Bulk Pack)

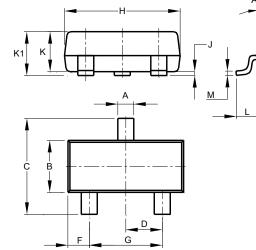




### Package Outline Dimensions (All dimensions in mm.)

Please see http://www.diodes.com/package-outlines.html for the latest version.

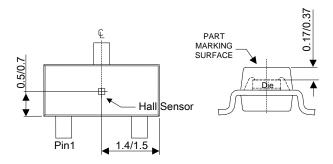
### (1) Package Type: SOT23



	All 7°		
		GAUGE P	
J		0.25	
<b>_</b>			
M			a
	└╶╾		L1

	SO	Г23	
Dim	Min	Max	Тур
Α	0.37	0.51	0.40
В	1.20	1.40	1.30
С	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
Н	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
М	0.085	0.150	0.110
а	0°	8°	
All [	Dimensi	ions in I	mm



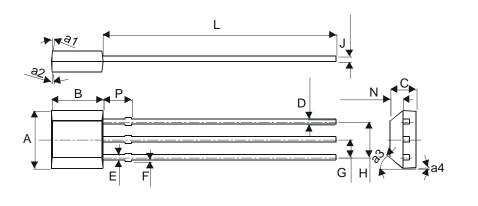


Sensor Location



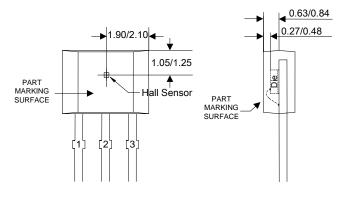
## Package Outline Dimensions (Cont.) (All dimensions in mm.)

### (2) Package Type: SIP-3 (Bulk Pack)



SIF	-3 (Bulk	Pack)
Dim	Min	Max
Α	3.9	4.3
a1	5°	Тур
a2	5°	Тур
a3	45°	<sup>,</sup> Тур
a4	3°	Тур
В	2.8	3.2
С	1.40	1.60
D	0.33	0.432
Е	0.40	0.508
F	0	0.2
G	1.24	1.30
Н	2.51	2.57
J	0.35	0.43
L	14.0	15.0
N	0.63	0.84
Р	1.55	-
All Di	mension	s in mm

Min/Max

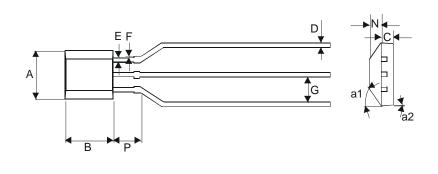


**Sensor Location** 



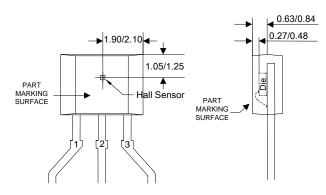
## Package Outline Dimensions (Cont.) (All dimensions in mm.)

### (3) Package Type: SIP-3 (Ammo Pack)



SIP-3 (Ammo Pack)		
Dim	Min	Max
Α	3.9	4.3
a1	45° Typ	
a2	3° Тур	
В	2.8	3.2
С	1.40	1.60
D	0.35	0.41
E	0.43	0.48
F	0	0.2
G	2.4	2.9
N	0.63	0.84
Р	1.55	-
All Dimensions in mm		





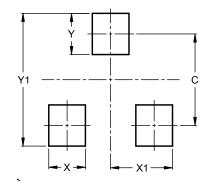
Sensor Location



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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